PATENT ASSIGNMENT

Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
SanDisk Corporation	04/04/2011

RECEIVING PARTY DATA

Name:	SanDisk Technologies Inc.
Street Address:	6900 North Dallas Parkway
Internal Address:	Two Legacy Town Center
City:	Plano
State/Country:	TEXAS
Postal Code:	75024

PROPERTY NUMBERS Total: 1

Property Type	Number
Patent Number:	7305535

CORRESPONDENCE DATA

Fax Number: (408)801-8512

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Phone: 4088012863

Email: simona.benjamin@sandisk.com

Correspondent Name: SanDisk Corporation

Address Line 1: 601 Mccarthy Boulevard

Address Line 2: Patent Department/Simona Benjamin

Address Line 4: Milpitas, CALIFORNIA 95035

ATTORNEY DOCKET NUMBER: SDK0299.000US

NAME OF SUBMITTER: Simona Benjamin

Total Attachments: 5

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PATENT REEL: 026317 FRAME: 0497 \$40.00 730

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ASSIGNMENT

WHEREAS, SanDisk Corporation, a Delaware corporation, doing business at 601 McCarthy Boulevard, Milpitas, CA 95035 (hereinafter referred to as ASSIGNOR), holds right, title and interest throughout the world in and to the patents and patent applications set forth in the attached Exhibit A, together with all divisions, continuations, or continuations-in-part thereof, and all patents issuing thereon including reissues, renewals, substitutions, re-examinations and extensions thereof, and any and all corresponding foreign patents and patent applications (hereinafter referred to as, collectively, THE ASSIGNED PATENT RIGHTS);

WHEREAS, SanDisk Technologies Inc., a Texas corporation, doing business at Two Legacy Town Center, 6900 North Dallas Parkway, Plano, Texas 75024, (hereinafter referred to as ASSIGNEE), is desirous of acquiring the full and exclusive right, title and interest in THE ASSIGNED PATENT RIGHTS;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, ASSIGNOR hereby assigns, transfers and conveys unto the said ASSIGNEE, and ASSIGNEE accepts, all of ASSIGNOR's right, title and interest throughout the world in and to THE ASSIGNED PATENT RIGHTS and to all Letters Patent or applications or similar legal protection, not only in the United States and its territorial possessions, but in all countries foreign thereto to be obtained for THE ASSIGNED PATENT RIGHTS, and to any continuation, division, renewal, substitute or reissue thereof or any legal equivalent thereof in the United States or a foreign country for the full term or terms for which the same may be granted, including all priority rights under the International Convention; and ASSIGNOR hereby authorizes and requests the United States Commissioner of Patents and Trademarks and any officials of foreign countries whose duty it is to issue patents on applications as aforesaid, to issue all patents for THE ASSIGNED PATENT RIGHTS to ASSIGNEE in accordance with the terms of this ASSIGNMENT but subject to reserved rights including but not limited to those previously retained by, granted to, or owned by, the United States government, educational institutions or both and hereby transfers and conveys all rights of action, power and benefit belonging to or accruing from THE ASSIGNED PATENT RIGHTS including the right to undertake proceedings to recover past and future damages and claim all other relief in respect of any acts of infringement thereof whether such acts shall have been committed before or after the date of this assignment.

No other rights, immunities, or licenses, including, without limitation, any rights to any intellectual property owned, controlled or licensable by **Assignor** are granted or assigned to ASSIGNEE under this ASSIGNMENT, either expressly or by implication, estoppel, or otherwise, other than the rights expressly recited herein.

ASSIGNOR hereby covenants that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would knowingly conflict with this Agreement;

ASSIGNOR further covenants that ASSIGNEE will, upon its lawful request, reasonably be provided with all pertinent facts and documents relating to THE ASSIGNED PATENT RIGHTS and legal equivalents as may be known and reasonably accessible to ASSIGNOR and that ASSIGNOR will testify as to the same in any administrative contest or litigation related thereto and will promptly execute and deliver to ASSIGNEE or its legal representative any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce THE ASSIGNED PATENT RIGHTS and said equivalents in the United States or in any foreign country, which may be necessary or desirable to carry out the purposes thereof.

IN TESTIMONY WHEREOF, I hereunto set my hand as of the date indicated below.

SANDISK CORPORATION

Dated: 4th April 2011	Andy Bruner Name: Judy Bruner Title: EVP and CFO
STATE OF California)ss.	
	ore me Area I Branson Watan (notary public) the undersigned Notary
within instrument and acknowledged to me that	nce to be the person(s) whose name(s) is/are subscribed to the he/she/they executed the same in his/her/their authorized the instrument the person(s), or the entity upon behalf of which
I certify under PENALTY OF PERJURY under the lar and correct.	ws of the State of California that the foregoing paragraph is true
	WITNESS my hand and official seal.
AVERIL BRANWEN WATAN Commission # 1742706 Notary Public - California Santa Clara County My Comm. Expires Apr 29, 2011	Signature: Signature of Notary Public
	We accept the Assignment
	SANDISK TECHNOLOGIES INC.
Dated: 4/4/11	Name: James F. Brelsford Title: President and Sceretary
STATE OF California)	· ·
STATE OF California COUNTY OF Santo Clora)ss.	
On this 4 day of April, 2011, before Public, personally appeared 1 fames f. Be	ore me the undersigned Notary
who proved to me on the basis of satisfactory evider	nce to be the person(s) whose name(s) is/are subscribed to the he/she/they executed the same in his/her/their authorized

capacity(ies), and that by his/her/their signature(s) on the instrument the person(s), or the entity upon behalf of which the person(s) acted, executed the instrument.

I certify under PENALTY OF PERJURY under the laws of the State of California that the foregoing paragraph is true and correct.

WITNESS my hand and official seal.

Signature: <u>Signature of Notary Public</u> L. BENJAMIN Commission # 1893105 Notary Public - California Santa Clara County

Exhibit A

FILE#	INVENTORS	TITLE	COUNTRY	STATUS	SER#	FILING DATE	PAT#	ISSUE DATE
SDK0298.002US	Raul-Adrian Cernea	Highly Compact Non-Volatile Memory And Method Thereof	US	Published	12274959	20-Nov-08		
DK0299.000US	Eliyahou Harari	Memory Cards Including A Standard Security Function	US	Issued	10418910	17-Apr-03	7305535	4-Dec-07
5DK0299.001US	Eliyahou Harari, Yoram Cedar, Wesley G. Brewer, Yosi Pinto, Reuven Elhamias, Michael Holtzman	Memory Cards Including A Standard Security Function	US	Published	11946558	28-Nov-07		
DK0300.000US	Nima Mokhlesi, Jeffrey Lutze	Alternate Sensing Techniques for Non-Volatile Memories	US	Issued	11321996	28-Dec-05	7349264	25-Mar-08
SDK0300.001US	Nima Mokhlesi, Jeffrey Lutze	Memories with Alternate Sensing Techniques	US	Issued	11320917	28-Dec-05	7616481	10-Nov-09
DK0300.002US	Nima Mokhlesi, Jeffrey Lutze	Alternate Sensing Techniques for Non-Volatile Memories	US	Issued	12023317	31-Jan-08	7460406	2-Dec-08
DK0301.000US	Nima Mokhlesi, Jeffrey Lutze	Pillar Cell Flash Memory	US	Issued	10732967	10-Dec-03	7049652	23-May-06
DK0301.001US	Nima Mokhlesi, Jeffrey Lutze	Pillar cell flash memory technology	US	Issued	11277907	29-Mar-06	7253055	7-Aug-07
5DK0302.000US	George Samachisa, Jack H. Yuan, Eliyahou Harari, Daniel Guterman	Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	10002696	31-Oct-01	6897522	24-May-05
DK0302.002US	George Samachisa, Jack H. Yuan, Eliyahou Harari, Daniel Guterman	Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	10280352	25-Oct-02	6925007	2-Aug-05
DK0302.003US	1 ' ' '	Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	11075423	7-Mar-05	7342279	11-Mar-08
DK0302.004US		Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	11075427	7-Mar-05	7341918	11-Mar-08
DK0302.005US		Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	12020266	25-Jan-08	7479677	20-Jan-09
DK0302.006US	· · · · · · · · · · · · · · · · · · ·	Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	12020296	25-Jan-08	7579247	25-Aug-09
DK0302.007US	· · · · · · · · · · · · · · · · · ·	Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements	US	Issued	12510077	27-Jul-09	7834392	16-Nov-10
DK0303.000US	Jian Chen, Long Pham, Alexander Mak	Techniques Of Recovering Data From Memory Cells Affected By Field Coupling With Adjacent Memory Cells	US	Issued	10052759	18-Jan-02	6542407	1-Apr-03
DK0303.001US	Jian Chen, Long Pham, Alexander Mak	Techniques of Recovering Data From Memory Cells Affected by Field Coupling with Adjacent Memory Cells	US	Issued	10357840	3-Feb-03	6847553	25-Jan-05
DK0303.002US	Jian Chen, Long Pham, Alexander Mak	Techniques of recovering data from memory cells affected by field coupling with adjacent memory cells	US	Issued	11028906	3-Jan-05	7102924	5-Sep-06
DK0304.000US	Reuven Elhamias, Andrew Tomlin, Wesley G. Brewer, Yosi Pinto, Michael Holtzman	Optimized Non-Volatile Storage Systems	US	Issued	10901849	28-Jul-04	7427027	23-Sep-08

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